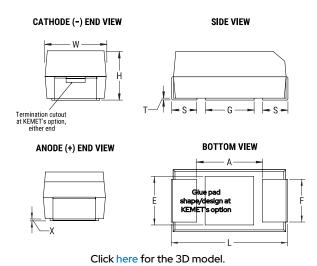


T5410157M030AH6720

T541 HRA, Tantalum, Polymer Tantalum, HRA Multi-Anode, 150 uF, 20%, 30 VDC, SMD, Polymer, Molded, High Reliability, Multi-Anode, Low ESR, N/A, 30 mOhms, 7360, 4.3 mm, 1.3 mm



General Information	
Series	T541HRA
Dielectric	Polymer Tantalum
Style	SMD Chip
Description	SMD, Polymer, Molded, High Reliability, Multi-Anode, Low ESR
Features	Non-Combustible, Multiple Anode, Low ESR, High Reliability
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov /
SCIP Number	b064b03e-bd75-42af-b342-1fe 94dec2340
Termination	Tin Lead (SnPb)
AEC-Q200	No
Shelf Life	52 Weeks
MSL	3

Dimensions	
L	7.3mm +/-0.3mm
W	6mm +/-0.3mm
Н	4mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	4.1mm +/-0.1mm
A	3.8mm MIN
E	3.5mm REF
G	3.5mm REF
X	0.1mm +/-0.1mm REF

G	3.5mm REF
X	0.1mm +/-0.1mm REF
Packaging Specifications	
Packaging Specifications Packaging	T&R, 178mm

Specifications	
Capacitance	150 uF
Tolerance	20%
Voltage DC	30 VDC (105C), 20.1 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	105°C
Life	2000 Hrs (125C)
Humidity	60C, 90% RH, 500 Hours, rated voltage
Dissipation Factor	10% 120Hz 25C
Failure Rate	N/A
ESR	30 mOhms (100kHz 25C)
Ripple Current	3160 mA (rms, 100kHz 45C)
Leakage Current	450 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C +0C/-5C And +85C +/-5C After Voltage Aging

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

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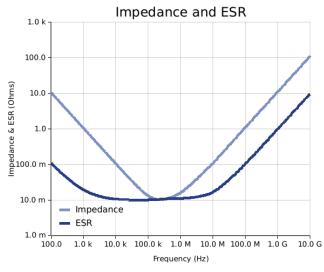


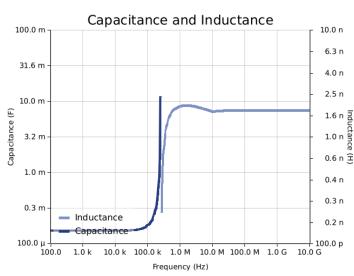
T5410157M030AH6720

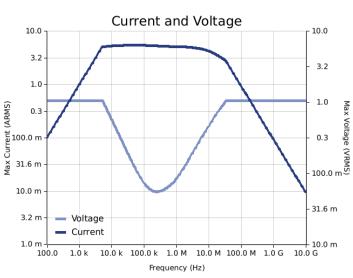
T541 HRA, Tantalum, Polymer Tantalum, HRA Multi-Anode, 150 uF, 20%, 30 VDC, SMD, Polymer, Molded, High Reliability, Multi-Anode, Low ESR, N/A, 30 mOhms, 7360, 4.3 mm, 1.3 mm

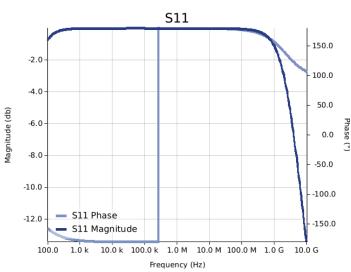
Simulations

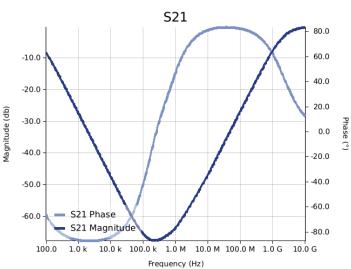
For the complete simulation environment please visit K-SIM.











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T5410157M030AH6720

T541 HRA, Tantalum, Polymer Tantalum, HRA Multi-Anode, 150 uF, 20%, 30 VDC, SMD, Polymer, Molded, High Reliability, Multi-Anode, Low ESR, N/A, 30 mOhms, 7360, 4.3 mm, 1.3 mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for ripple Ripple Currenty votage vs. rrequency plots is unleast at an interact temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.

 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

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Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.

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